<u>MOSFET</u> – Power, N-Channel, DPAK

14 A, 25 V

Features

- Planar HD3e Process for Fast Switching Performance
- Low R_{DS(on)} to Minimize Conduction Loss
- Low Ciss to Minimize Driver Loss
- Low Gate Charge
- Optimized for High Side Switching Requirements in High–Efficiency DC–DC Converters
- NVD and SVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	25	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	±20	Vdc
$\begin{array}{l} \mbox{Thermal Resistance - Junction-to-Case} \\ \mbox{Total Power Dissipation } @ T_A = 25^{\circ}C \\ \mbox{Drain Current - Continuous } @ T_A = 25^{\circ}C, \mbox{Chip} \\ \mbox{- Continuous } @ T_A = 25^{\circ}C, \mbox{Limited by Package} \\ \mbox{- Single Pulse (tp \leq 10 \ \mu s) \end{array}$	R _{θJC} P _D I _D I _D	6.0 20.8 14 11.4 28	°C/W W A A A
Thermal Resistance, Junction-to-Ambient (Note 1) Total Power Dissipation @ T _A = 25°C Drain Current – Continuous @ T _A = 25°C	R _{θJA} P _D I _D	80 1.56 3.1	°C/W W A
Thermal Resistance, Junction-to-Ambient (Note 2) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current – Continuous @ $T_A = 25^{\circ}C$	R _{θJA} P _D I _D	120 1.04 2.5	°C/W W A
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to 150	°C
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C

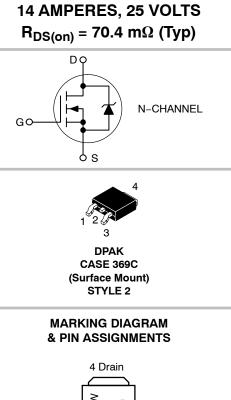
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

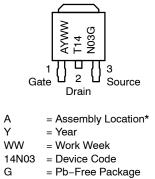
- 1. When surface mounted to an FR4 board using 0.5 sq. in pad size.
- 2. When surface mounted to an FR4 board using minimum recommended pad size.



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* The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package, the front side assembly code may be blank.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS			-	•	-	
Drain-to-Source Breakdown Voltage (Note 3) (V _{GS} = 0 Vdc, I _D = 250 μAdc) Temperature Coefficient (Positive)		V(br) _{DSS}	25 -	28 -		Vdc mV/°C
Zero Gate Voltage Drain Current (V_{DS} = 20 Vdc, V_{GS} = 0 Vdc) (V_{DS} = 20 Vdc, V_{GS} = 0 Vdc, T_J = 150°C)		I _{DSS}			1.0 10	μAdc
Gate–Body Leakage Current (V _{GS} = ±20 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	±100	nAdc
ON CHARACTERISTICS (Note	- 3)					
Gate Threshold Voltage (Note 3) $(V_{DS} = V_{GS}, I_D = 250 \mu Adc)$ Threshold Temperature Coefficient (Negative)		V _{GS(th)}	1.0 -	1.5 _	2.0	Vdc mV/°C
Static Drain-to-Source On-Resistance (Note 3) (V_{GS} = 4.5 Vdc, I_D = 5 Adc) (V_{GS} = 10 Vdc, I_D = 5 Adc)		R _{DS(on)}		117 70.4	130 95	mΩ
Forward Transconductance (Note 3) $(V_{DS} = 10 \text{ Vdc}, I_D = 5 \text{ Adc})$		9 _{FS}	_	7.0	_	Mhos
DYNAMIC CHARACTERISTIC	S					
Input Capacitance		C _{iss}	-	115	-	pF
Output Capacitance	$(V_{DS}$ = 20 Vdc, V_{GS} = 0 V, f = 1 MHz)	C _{oss}	-	62	-	
Transfer Capacitance		C _{rss}	-	33	-	
SWITCHING CHARACTERIST	ICS (Note 4)					
Turn-On Delay Time		t _{d(on)}	-	3.8	-	ns
Rise Time	(V _{GS} = 10 Vdc, V _{DD} = 10 Vdc,	t _r	-	27	-	
Turn-Off Delay Time	$I_D = 5 \text{ Adc}, R_G = 3 \Omega$)	t _{d(off)}	-	9.6	-	
Fall Time		t _f	-	2.0	-	1
Gate Charge		Q _T	-	1.8	-	nC
	$(V_{GS} = 5 \text{ Vdc}, I_D = 5 \text{ Adc}, V_{DS} = 10 \text{ Vdc})$ (Note 3)	Q ₁	-	0.8	-	
		Q ₂	-	0.7	-	
SOURCE-DRAIN DIODE CHA	RACTERISTICS					
Forward On-Voltage	$(I_S = 5 \text{ Adc}, V_{GS} = 0 \text{ Vdc}) \text{ (Note 3)}$ $(I_S = 5 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C})$	V_{SD}		0.93 0.82	1.2 -	V _{dc}
Reverse Recovery Time		t _{rr}	-	6.6	-	ns
	(I _S = 5 Adc, V _{GS} = 0 Vdc,	t _a	-	4.75	-	
	$dI_S/dt = 100 \text{ A/}\mu\text{s}$ (Note 3)	t _b	-	1.88	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. 4. Switching characteristics are independent of operating junction temperatures.

t_b

 $\mathsf{Q}_{\mathsf{R}\mathsf{R}}$

0.002

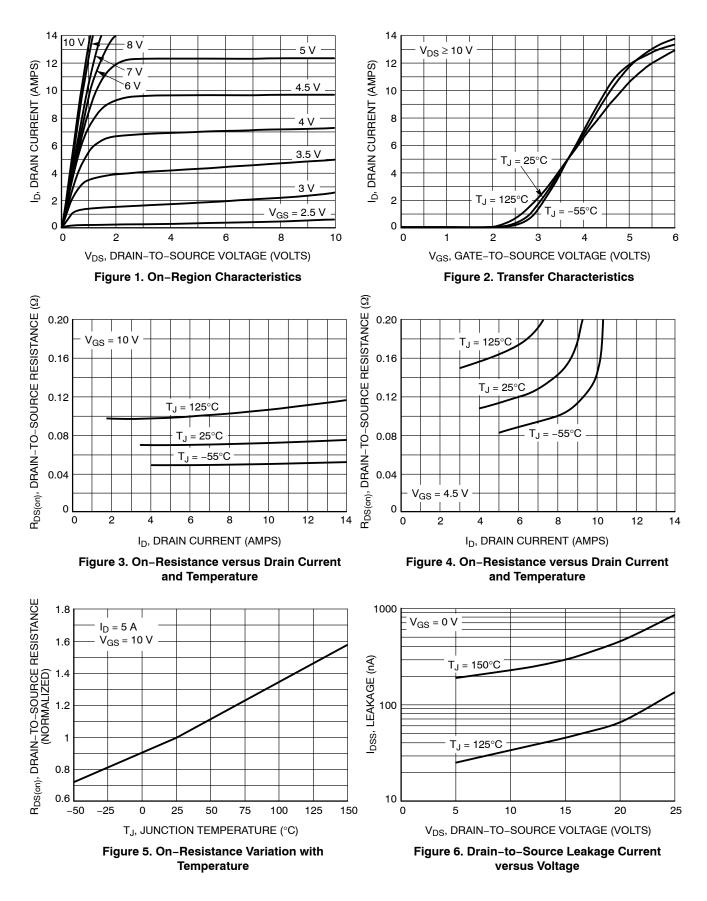
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μC

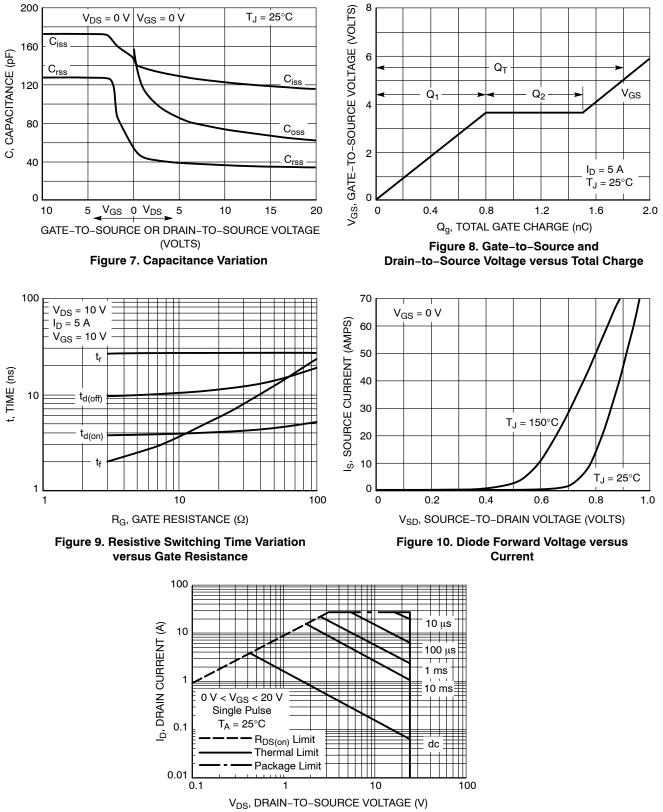
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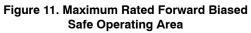
Reverse Recovery Stored Charge

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





TYPICAL CHARACTERISTICS

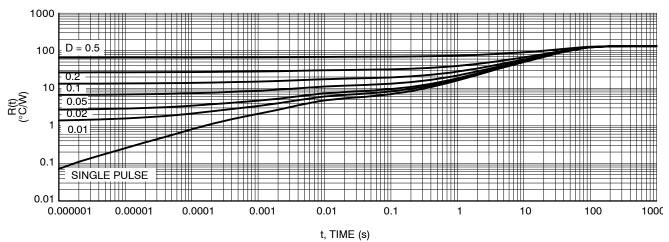


Figure 12. Thermal Response

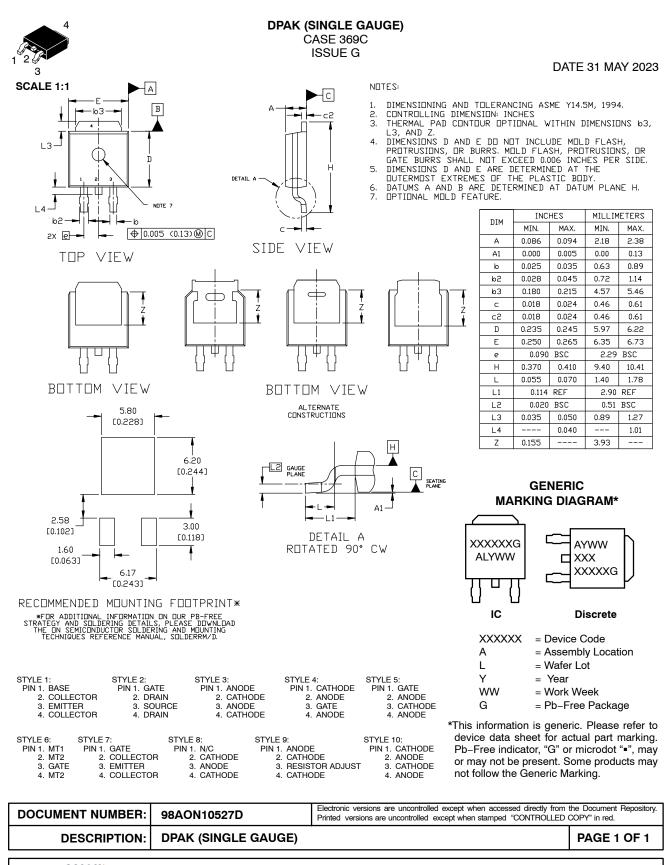
ORDERING INFORMATION

Device	Package	Shipping [†]	
NTD14N03RT4G	DPAK (Pb-Free)	2500 / Tape & Reel	
NVD14N03RT4G*	DPAK (Pb-Free)	2500 / Tape & Reel	
SVD14N03RT4G*	DPAK (Pb–Free)	2500 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NVD and SVD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

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